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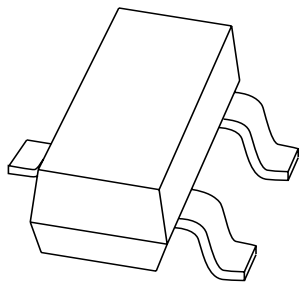
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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via salesaddresses@nexperia.com). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DATA SHEET



BC856; BC857; BC858 PNP general purpose transistors

Product data sheet
Supersedes data of 2003 Apr 09

2004 Jan 16

PNP general purpose transistors

BC856; BC857; BC858

FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 65 V).

APPLICATIONS

- General purpose switching and amplification.

DESCRIPTION

PNP transistor in a SOT23 plastic package.
NPN complements: BC846, BC847 and BC848.

MARKING

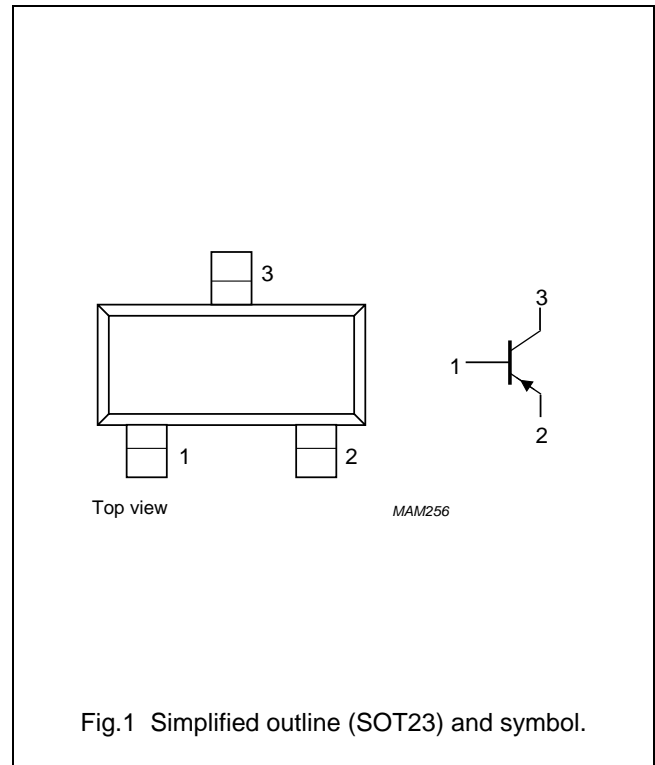
| TYPE NUMBER | MARKING CODE ⁽¹⁾ |
|-------------|-----------------------------|
| BC856 | 3D* |
| BC856A | 3A* |
| BC856B | 3B* |
| BC857 | 3H* |
| BC857A | 3E* |
| BC857B | 3F* |
| BC857C | 3G* |
| BC858B | 3K* |

Note

- * = p: made in Hong Kong.
* = t: made in Malaysia.
* = W: made in China.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | base |
| 2 | emitter |
| 3 | collector |



ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | |
|-------------|---------|--|---------|
| | NAME | DESCRIPTION | VERSION |
| BC856 | – | plastic surface mounted package; 3 leads | SOT23 |
| BC857 | – | plastic surface mounted package; 3 leads | SOT23 |
| BC858 | – | plastic surface mounted package; 3 leads | SOT23 |

PNP general purpose transistors

BC856; BC857; BC858

LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------|----------------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | | | |
| | BC856 | | – | –80 | V |
| | BC857 | | – | –50 | V |
| | BC858 | | – | –30 | V |
| V _{CEO} | collector-emitter voltage | open base | | | |
| | BC856 | | – | –65 | V |
| | BC857 | | – | –45 | V |
| | BC858 | | – | –30 | V |
| V _{EBO} | emitter-base voltage | open collector | – | –5 | V |
| I _C | collector current (DC) | | – | –100 | mA |
| I _{CM} | peak collector current | | – | –200 | mA |
| I _{BM} | peak base current | | – | –200 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C; note 1 | – | 250 | mW |
| T _{stg} | storage temperature | | –65 | +150 | °C |
| T _j | junction temperature | | – | 150 | °C |
| T _{amb} | operating ambient temperature | | –65 | +150 | °C |

Note

1. Transistor mounted on an FR4 printed-circuit board, standard footprint.

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | TYPICAL | UNIT |
|----------------------|---|---------------------|---------|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air; note 1 | 500 | K/W |

Note

1. Transistor mounted on an FR4 printed-circuit board, standard footprint.

PNP general purpose transistors

BC856; BC857; BC858

CHARACTERISTICS

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

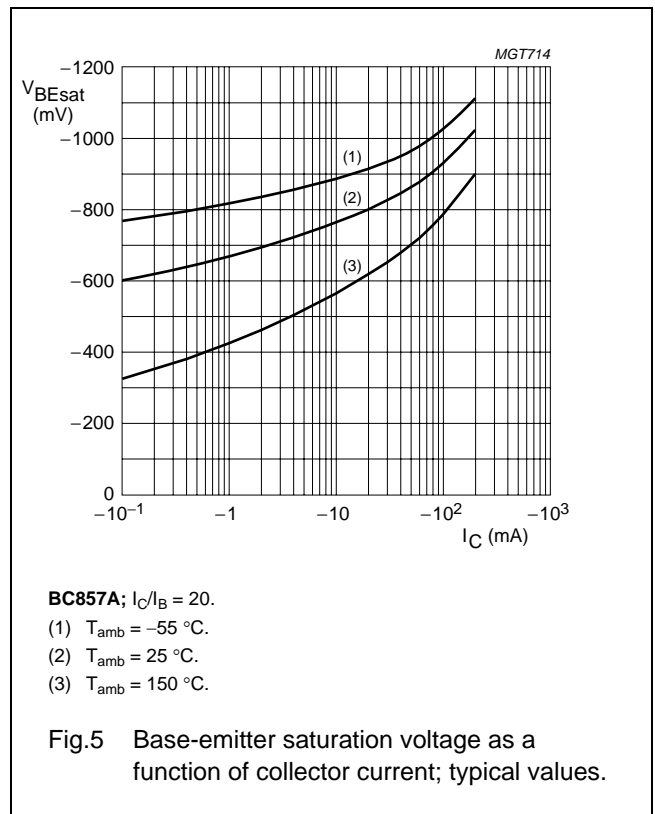
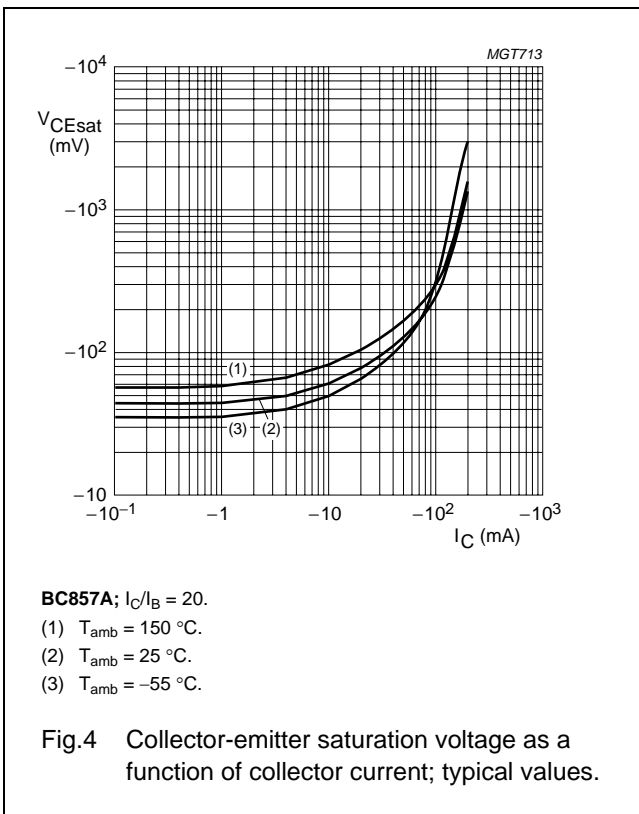
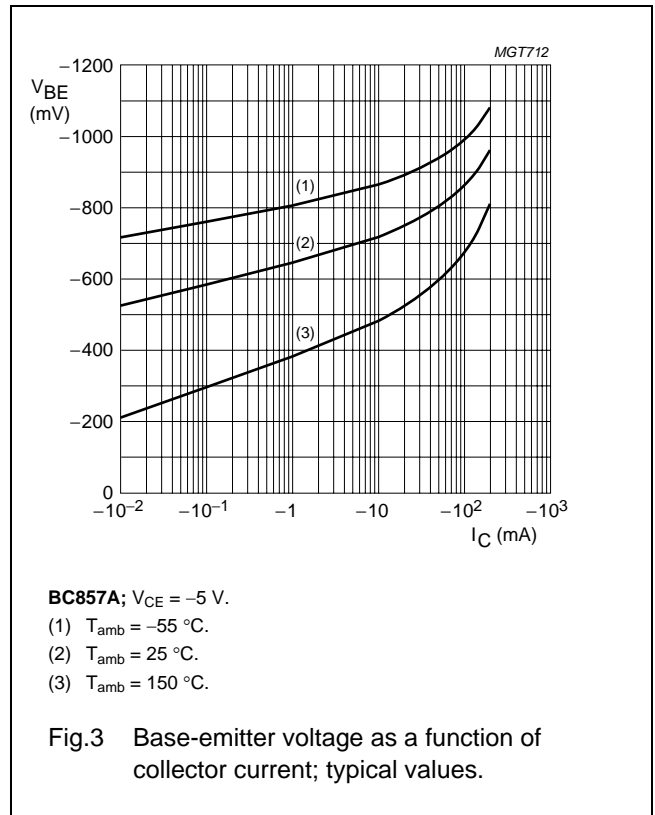
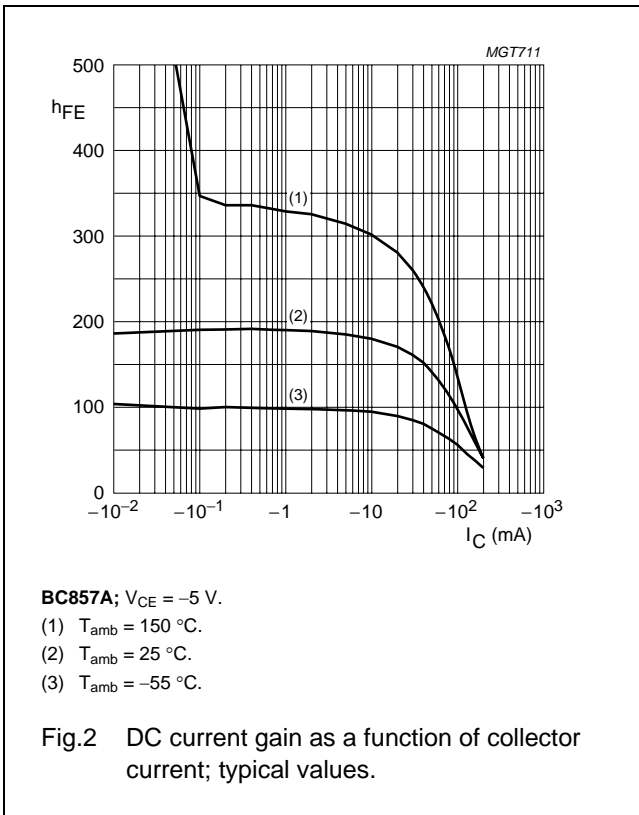
| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT | | | | |
|-------------|--------------------------------------|--|------|------|------|---------------|------------------------|-----|---|-----|
| I_{CBO} | collector-base cut-off current | $V_{CB} = -30\text{ V}; I_E = 0$ | – | –1 | –15 | nA | | | | |
| | | $V_{CB} = -30\text{ V}; I_E = 0;$ $T_j = 150\text{ °C}$ | – | – | –4 | μA | | | | |
| I_{EBO} | emitter-base cut-off current | $V_{EB} = -5\text{ V}; I_C = 0$ | – | – | –100 | nA | | | | |
| h_{FE} | DC current gain | $I_C = -2\text{ mA}; V_{CE} = -5\text{ V}$ | | | | | | | | |
| | | | | | | | BC856 | 125 | – | 475 |
| | | | | | | | BC857 | 125 | – | 800 |
| | | | | | | | BC856A; BC857A | 125 | – | 250 |
| | | | | | | | BC856B; BC857B; BC858B | 220 | – | 475 |
| BC857C | 420 | – | 800 | | | | | | | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = -10\text{ mA}; I_B = -0.5\text{ mA}$ | – | –75 | –300 | mV | | | | |
| | | $I_C = -100\text{ mA}; I_B = -5\text{ mA};$ note 1 | – | –250 | –650 | mV | | | | |
| V_{BEsat} | base-emitter saturation voltage | $I_C = -10\text{ mA}; I_B = -0.5\text{ mA}$ | – | –700 | – | mV | | | | |
| | | $I_C = -100\text{ mA}; I_B = -5\text{ mA};$ note 1 | – | –850 | – | mV | | | | |
| V_{BE} | base-emitter voltage | $I_C = -2\text{ mA}; V_{CE} = -5\text{ V}$ | –600 | –650 | –750 | mV | | | | |
| | | $I_C = -10\text{ mA}; V_{CE} = -5\text{ V}$ | – | – | –820 | mV | | | | |
| C_c | collector capacitance | $V_{CB} = -10\text{ V}; I_E = I_e = 0;$ $f = 1\text{ MHz}$ | – | 4.5 | – | pF | | | | |
| f_T | transition frequency | $V_{CE} = -5\text{ V}; I_C = -10\text{ mA};$ $f = 100\text{ MHz}$ | 100 | – | – | MHz | | | | |
| F | noise figure | $I_C = -200\text{ }\mu\text{A}; V_{CE} = -5\text{ V};$ $R_S = 2\text{ k}\Omega; f = 1\text{ kHz};$ $B = 200\text{ Hz}$ | – | 2 | 10 | dB | | | | |

Note

1. Pulse test: $t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$.

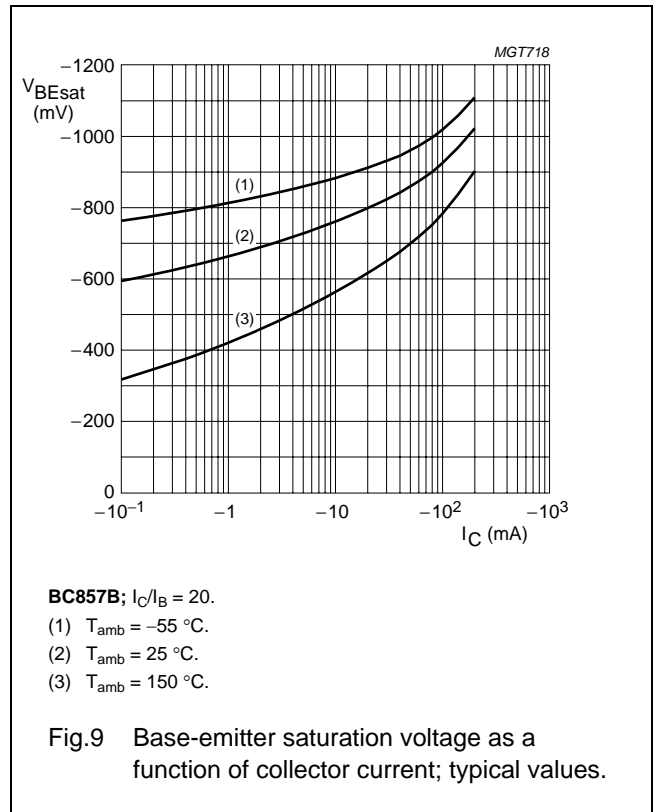
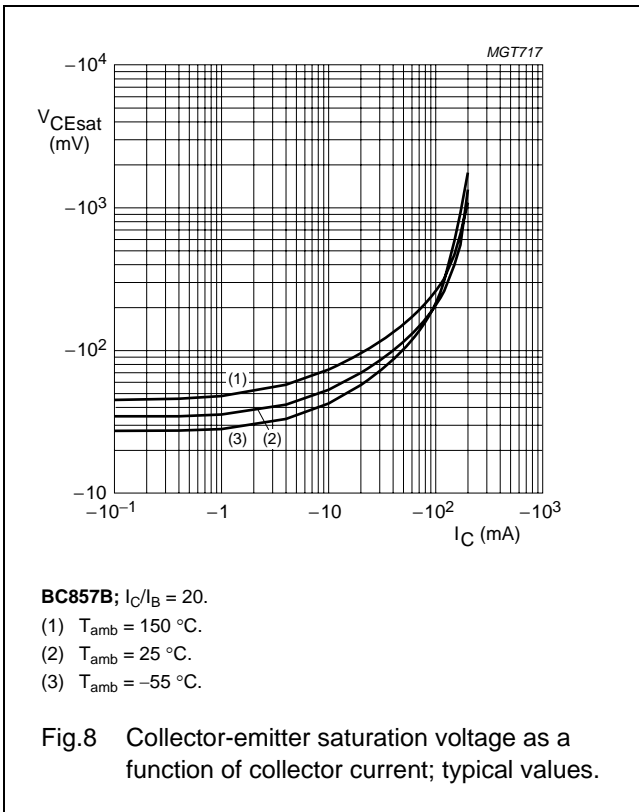
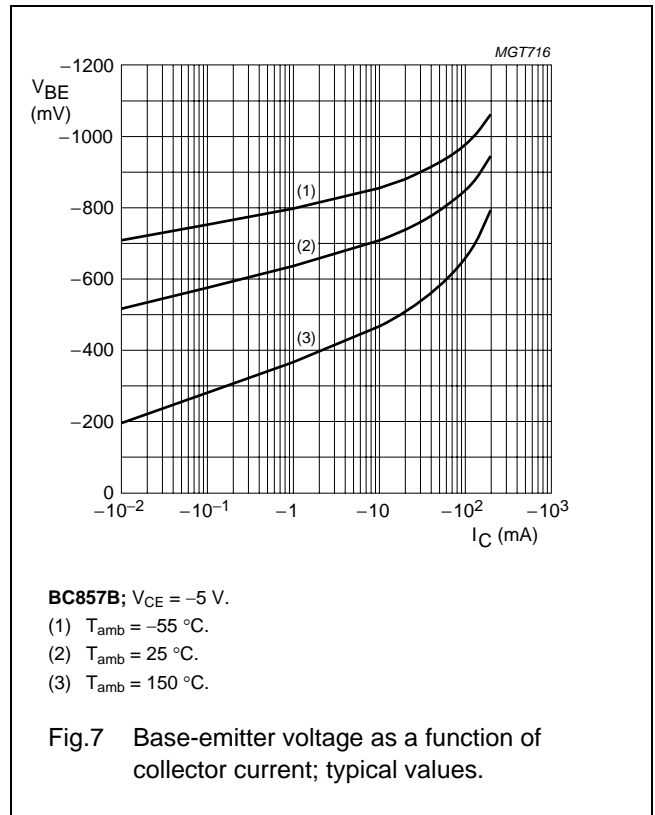
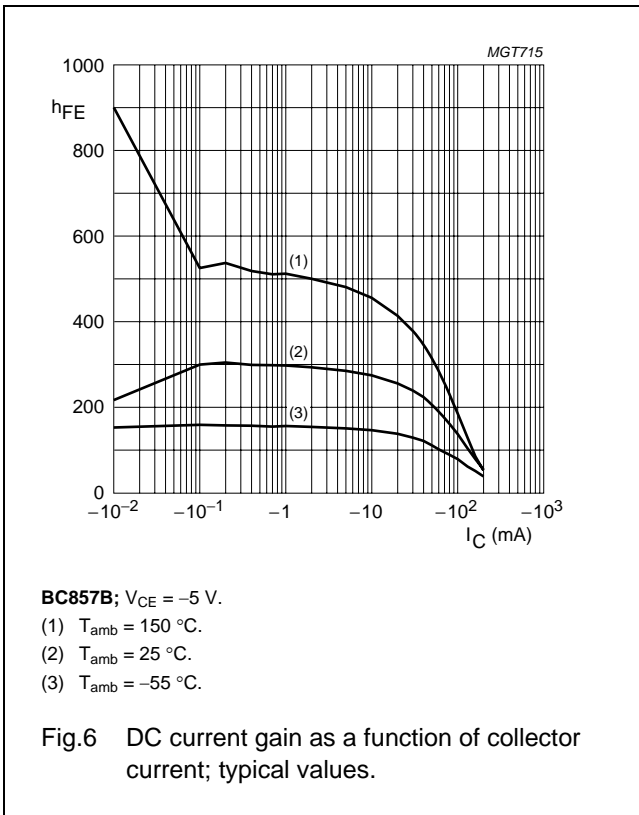
PNP general purpose transistors

BC856; BC857; BC858



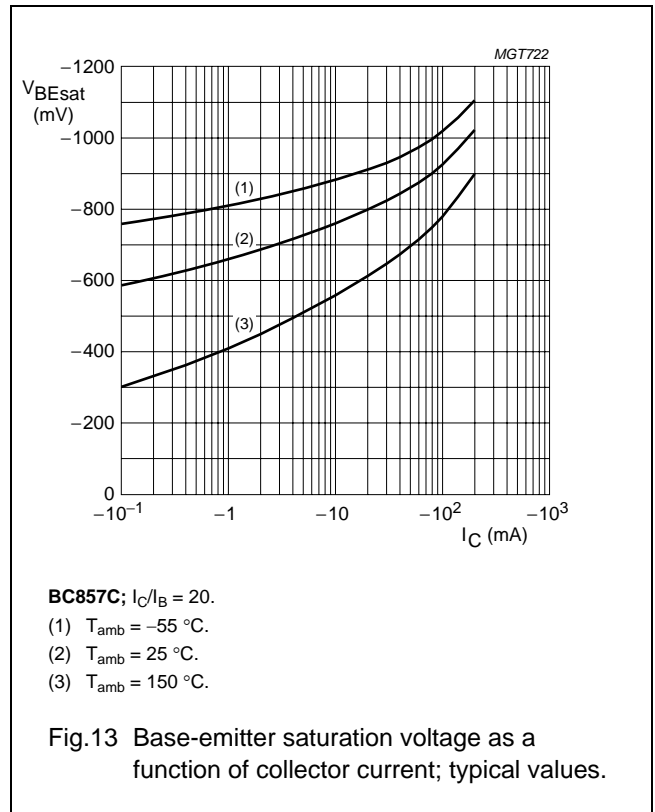
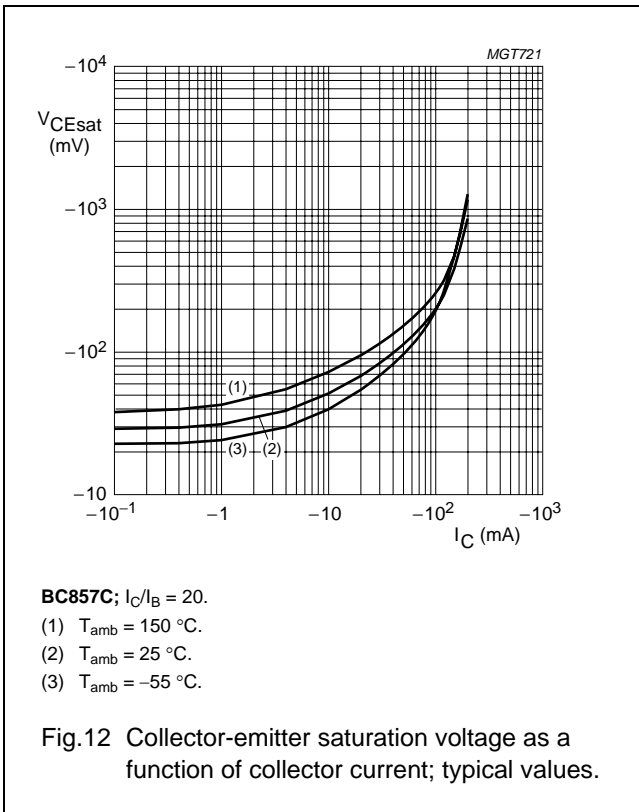
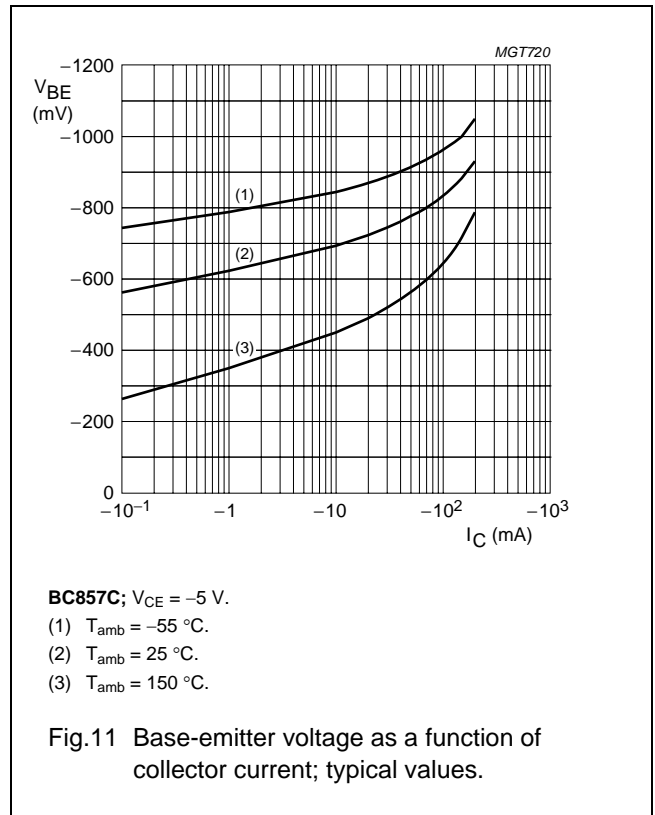
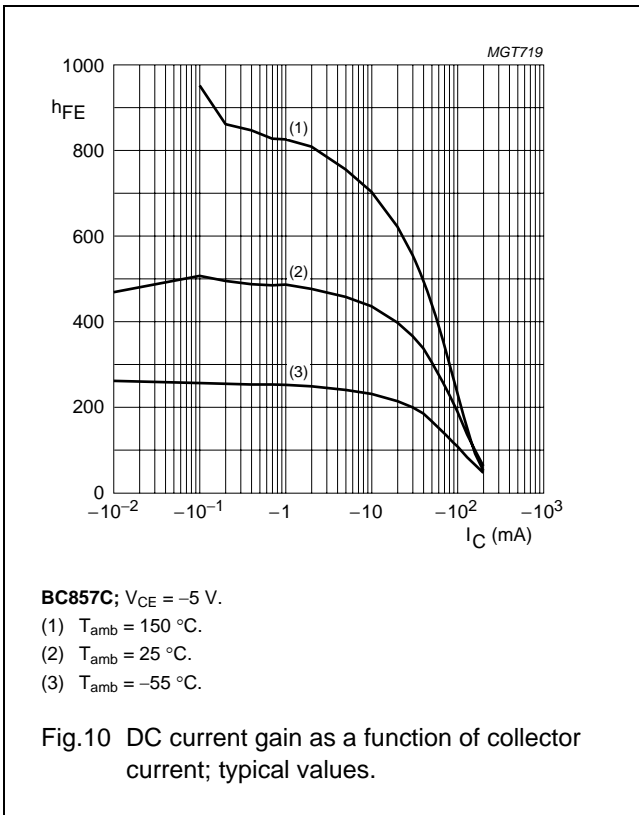
PNP general purpose transistors

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PNP general purpose transistors

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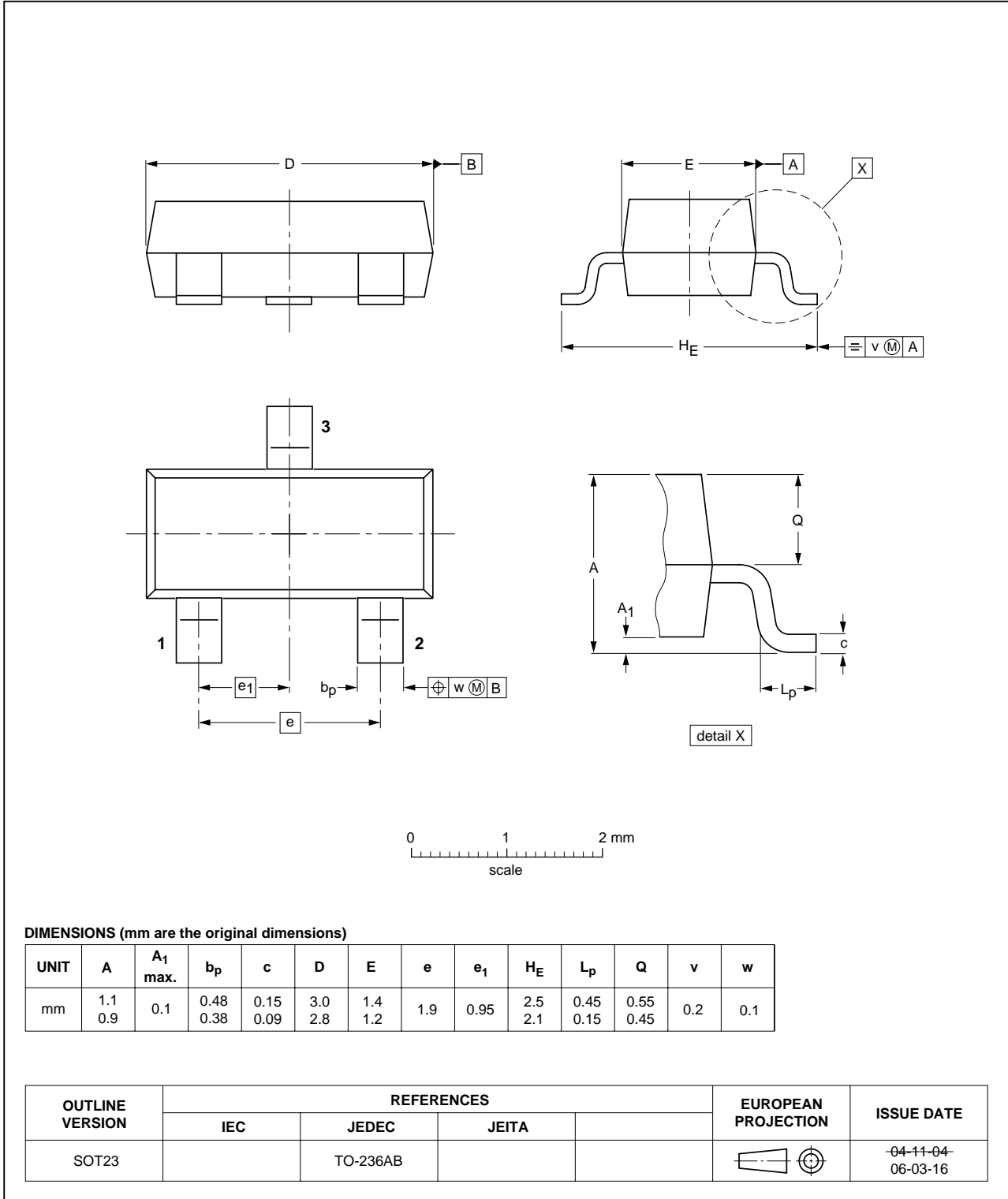
PNP general purpose transistors

BC856; BC857; BC858

PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads

SOT23



PNP general purpose transistors

BC856; BC857; BC858

DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|--------------------------------|-------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: <http://www.nxp.com>

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